# REscope: High-dimensional Statistical Circuit Simulation towards Full Failure Region Coverage

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## Need & Challenge of High Sigma analysis

- Need for statistical circuit analysis
  - Process technology continue to scale 45nm, 32nm, -22nm ...
    - Shrinking devices 
       → more prone to PVT variations
  - Statistical circuit analysis helps to debug circuits in the pre-silicon phase, and enhances yield rate
- **Challenges: High Sigma** (Rare Failure Event) analysis
  - Memory cell (e.g. 6+ sigma)

Percen

Critical circuits (e.g. 4-5 sigma): I/O cell, PLL, etc.





Courtesy of Prof. Yiming Li, National Chiao Tung University, Taiwan

700

4,400

74,100

3,157,500

348,855,600

[LYL09] Kyu Won Lee, SM Yoon, SC Lee, W Lee, IM Kim, Cheol Eui Lee, and DH Kim. "Secondary electron eneration in electron-beam-irradiated solids: Resolution limits to nanolithography." J Korean Phys Soc, 55:1720–1723, 2009

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## **Existing Approaches**

- Monte Carlo Simulation:
  - Monte Carlo is infeasible for high sigma analysis in terms of computational complexity
    - One post-layout PLL simulation may take several hours
- Importance Sampling methods:
  - Shift the sample distribution to more "important" region
  - e.g. Spherical sampling<sup>[QTD10]</sup>, HDIS<sup>[WGC14]</sup>
- Classification based methods:
  - Statistical Blockade (Linear classifier)<sup>[SR08]</sup>

[QTD10] M. Qazi, M. Tikekar, L. Dolecek, D. Shah, and A. Chandrakasan, "Loop flattening and spherical sampling: Highly efficient model reduction techniques for SRAM yield analysis," in DATE'2010, pp. 801–806. [12] W. Wu, F. Gong, G. Chen, and Lei He, "A Fast and Provably Bounded Failure Analysis of Memory Circuits in High Dimensions", ASPDAC'2014 [SR08] A Singhee, and RA Rutenbar. "Statistical blockade: Very fast statistical simulation and modeling of rare circuit events and its application to memory design," in DATE'2008, pp. 235-251.



#### What if there are multiple failure regions ?

What if failure samples fall in multiple disjoint regions

Importance sampling works like this:

 Statistical blockade can't identify multiple failure regions. Even worse, the classifier scales poorly with the number of variation variables





#### Unfortunately, multiple failure regions do exist

MP1

MN4

MN3

GND

Up

Dn

MP2

SW1

SW2

MN5

Out

![](_page_4_Figure_1.jpeg)

PFD: phase frequency detector; CP FD: frequency divider; VC

**CP: Charge pump** VCO: voltage controlled oscillator

![](_page_4_Figure_4.jpeg)

Mismatch between MP2 and MN5 may result in fluctuation of control voltage, which will lead to "jitter" in the clock.

Vths of MP2 and MN5 are variation parameters

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#### Rare-Event Microscope (REscope)

- Make the classification based approach more practical, in terms of accuracy and efficiency.
  - Identifies multiple failure regions
  - Handles high dimensional problems
  - Approximates the tail as a generalized pareto distribution (GPD)
    - GPD: a good model for the distribution of the exceedence to a certain threshold in another distribution, i.e. the tail of PDF(y)

![](_page_5_Figure_6.jpeg)

## Pruning and Classification

- Parameter pruning (Feature selection)
  - Evaluate the "Importance" of each parameter (feature)
  - RELIEF-F algorithm:

Pre-sampling

- $W_i = W_i + (x_i nearMiss_i)^2 (x_i nearHit_i)^2$
- Sort parameters by "Importance", and prune the unimportant parameters

#### Classification

Distribution of

process variation

parameters

- The boundary separating accept and failure regions is usually nonlinear
- Apply support vector machine (SVM) with radial basis function (RBF) kernel yields a good nonlinear boundary

Parameter

Pruning

![](_page_6_Figure_9.jpeg)

#### Calculate W<sub>2</sub>

Tail Distribution

Estimation

x,-nearMiss,

Classification

![](_page_6_Figure_11.jpeg)

Failure

probability

#### **GPD** Approximation

- Approximate the tail of PDF by GPD with only 2 parameters
  - Shape parameter(ξ), scale parameter(σ), starting point of the tail(μ)

$$F_{(\xi,\mu,\sigma)}(y) = \begin{cases} 1 - \left(1 - \frac{\xi(y-\mu)}{\sigma}\right)^{\frac{1}{\xi}} & for \ \xi \neq 0\\ 1 - \exp\left(-\frac{(y-\mu)}{\sigma}\right) & for \ \xi = 0 \end{cases}$$
(5)

- Calculate the initial solution by probability weighted moment matching
- Refine the solution by Newton's method

![](_page_7_Figure_6.jpeg)

![](_page_7_Figure_7.jpeg)

![](_page_7_Picture_8.jpeg)

#### Experiments: REscope for Charge Pump

- One circuit, two configurations
  - An illustrative example: only 2 variation parameters
    - Vth of MP2 and MN5
  - A high dimensional example: **108** process variation parameters (27 transistors, 4 process variation parameters for each)
    - Channel length
    - Channel weight
    - Gate oxide thickness
    - Flat-band voltage
- Failure: current mismatch.

![](_page_8_Figure_10.jpeg)

#### **Experiment 1: Illustration of Classification results**

![](_page_9_Figure_1.jpeg)

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#### Experiment 2: Handling high dimensional cases

- Parameter pruning results:
  - 27 important features are selected out of 108 variables

![](_page_10_Figure_3.jpeg)

Figure 7: Weight of all 108 process variations in charge pump circuit

#### Accuracy of REscope

 Tail modeling after parameter pruning:

![](_page_11_Figure_2.jpeg)

1.13

CDF tail in log scale

1.14

1.12

2.5

1.08

1.09

(b)

1 1

1.11

-MC

1.15 1.16

REscope

Mismatch after 4.2 sigma because we don't have enough MC samples so far.

The estimated P<sub>fail</sub>

overlap with MC

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#### Comparison with existing methods

Table 1: Comparison of the accuracy and efficiency on charge pump circuit

	Monte Carlo (MC)	Importance sampling (HDIS)[12]	Proposed approach (REscope)
failure probability	2.279e-5 (0%)	1.136e-3	2.256e-5 (+1.05%)
#sim. runs	1.4e+6 (389x)	2e+4 (5.6x)	3.6e+3 (1x)

 389x speedup on MC with 1.05% error at 4 sigma, while importance sampling and statistical blockade fail.

[12] Wei Wu, Fang Gong, Gengsheng Chen, and Lei He, "A Fast and Provably Bounded Failure Analysis of Memory Circuits in High Dimensions", ASPDAC'2014

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## Conclusions

#### Strength:

- Dimension reduction algorithm keeps the "important" parameters only.
- Nonlinear classifier works perfectly on detecting multiple failure regions.
- The tail is explicitly matched to a known distribution, such as GPD, to further reduce the number of sample.
- Experiments show 389x speedup on MC with only 1.05% error, which importance sampling and statistical blockade fail.

- Limitation and Future direction:
  - Considering the correlation between variations sources
  - Algorithm to automatically adjust the classifier configuration

# Thanks!

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